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APPLICATION NO.	FILING DATE		FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/740,205	40,205 12/18/2003		Krishnaswamy Ramkumar	5298-08101 PM01039D	2236	
35617	7590	06/29/2004		EXAMINER		
CONLEY P.O. BOX 68	•		PHAM, HOAI V			
AUSTIN, T				ART UNIT	PAPER NUMBER	
,				2814		
				DATE MAILED: 06/29/2004		

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application	n No.	Applicant(s)	-				
		10/740,20	5	RAMKUMAR ET AL.					
	Office Action Summary	Examiner		Art Unit					
		Hoai V Ph		2814					
Period fo	The MAILING DATE of this communication or Reply	appears on the	cover she t with the c	correspondence ad	ddress				
THE   - Exter after - If the - If NO - Failu Any I	ORTENED STATUTORY PERIOD FOR REMAILING DATE OF THIS COMMUNICATIOnsions of time may be available under the provisions of 37 CFI SIX (6) MONTHS from the mailing date of this communication period for reply specified above is less than thirty (30) days, at period for reply is specified above, the maximum statutory pere to reply within the set or extended period for reply will, by streply received by the Office later than three months after the med patent term adjustment. See 37 CFR 1.704(b).	DN. R 1.136(a). In no eve I. I reply within the statu I riod will apply and wi I atute, cause the appl	ent, however, may a reply be tin story minimum of thirty (30) day Il expire SIX (6) MONTHS from ication to become ABANDONE	nely filed rs will be considered time the mailing date of this of D (35 U.S.C. § 133).	ely. communication.				
Status									
1)⊠	Responsive to communication(s) filed on 1	8 December 20	<u>)03</u> .						
2a) <u></u> □	This action is <b>FINAL</b> . 2b)	This action is n	action is non-final.						
3)	3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is								
	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.								
Dispositi	ion of Claims								
4) 🖂	4)⊠ Claim(s) <u>17-20</u> is/are pending in the application.								
	4a) Of the above claim(s) is/are withdrawn from consideration.								
5) 🗌	5) Claim(s) is/are allowed.								
6)⊠	6)⊠ Claim(s) <u>17,18 and 20</u> is/are rejected.								
· · · · · · · · · · · · · · · · · · ·	Claim(s) <u>19</u> is/are objected to.								
8)∐	Claim(s) are subject to restriction ar	nd/or election re	equirement.						
Applicati	ion Papers								
9)	The specification is objected to by the Exan	niner.							
10)⊠ The drawing(s) filed on <u>18 December 2003</u> is/are: a)⊠ accepted or b)□ objected to by the Examiner.									
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).									
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).									
11)	The oath or declaration is objected to by the	e Examiner. No	te the attached Office	Action or form P	TO-152.				
Priority u	under 35 U.S.C. § 119								
12)	Acknowledgment is made of a claim for fore	eign priority und	der 35 U.S.C. § 119(a	)-(d) or (f).					
a) ☐ All b) ☐ Some * c) ☐ None of:									
1. Certified copies of the priority documents have been received.									
	2. Certified copies of the priority docum	nents have bee	n received in Applicati	ion No					
	3. Copies of the certified copies of the			ed in this National	l Stage				
	application from the International Bu	•	' ''						
* 5	See the attached detailed Office action for a	list of the certi	ied copies not receive	ed.					
Attachmen									
	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948)	)	4) Interview Summary Paper No(s)/Mail D						
3) 🛛 Inform	nation Disclosure Statement(s) (PTO-1449 or PTO/SB r No(s)/Mail Date <u>4/13/04</u> .		5) Notice of Informal F 6) Other:		O-152)				

### **DETAILED ACTION**

# Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 2. Claims 17-18 and 20 rejected under 35 U.S.C. 102(e) as being anticipated by Kunikiyo [U.S. Pat. 6,661,065].

With respect to claim 17, Kunikiyo (fig. 21, cols. 22-23) discloses a silicon-oxide-nitride-oxide-silicon structure (see col. 22, lines 66-67 and col. 23, line 1) comprising a first oxide layer (111) arranged upon a silicon-based semiconductor substrate (1), wherein an interface between the silicon-based semiconductor substrate and the first oxide layer comprises deuterium (see col. 19, lines 13-16).

With respect to claim 18, Kunikiyo inherently discloses a lateral length of the interface between the silicon-based semiconductor substrate (1) and the first oxide layer (111) is bound by opposing sidewalls of the structure, and wherein said deuterium is arranged across an entirety of said lateral length.

With respect to claim 20, Kunikiyo discloses that the nitride layer (121) comprises deuterium (see col. 22, line 46).

Application/Control Number: 10/740,205 Page 3

Art Unit: 2814

# Allowable Subject Matter

3. Claim 19 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

4. The following is an examiner's statement of reasons for allowance: the prior of record fails to disclose the combination of a semiconductor device structure recited in the base claim 17, including the combination of the structure comprising: a nitride layer arranged upon and in contact with the first oxide layer; a second oxide layer arranged upon and in contact with the nitride layer, and a second silicon layer arranged upon and in contact with the second oxide layer, wherein an interface between the second silicon layer and second oxide layer comprises deuterium.

### Conclusion

- 5. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Hoai V Pham whose telephone number is 571-272-1715. The examiner can normally be reached on 9:30A.M. 8:00P.M..
- 6. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael M. Fahmy can be reached on 571-272-1705. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Application/Control Number: 10/740,205 Page 4

Art Unit: 2814

7. Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic

Business Center (EBC) at 866-217-9197 (toll-free).

Hoai Pham

Patent Examiner